

Solid State Devices, Inc.

14701 Firestone Blvd * La Mirada, Ca 90638 Phone: (562) 404-4474 * Fax: (562) 404-1773 ssdi@ssdi-power.com * www.ssdi-power.com

DESIGNER'S DATA SHEET

Part Number / Ordering Information 1/ SPD5 L Screening^{2/} = None TX = TX Level TXV = TXV Level S = S Level **Package** __ = Axial Leaded SMS = Surface Mount Square Tab Voltage $02 = 200 \ V$ 03 = 300 V04 = 400 V05 = 500 V06 = 600V

SPD502-SPD506 SPD502SMS - SPD506SMS

5 AMP 200-600 Volts 40 nsec **HYPER FAST RECTIFIER**

Features:

- Hyper Fast Recovery: 40 nsec Max.
- PIV to 600 Volts
- Low Forward Voltage Drop
- Void Free Construction
- Hermetically Sealed Surface Mount Package
- For High Efficiency Applications
- Single Chip Construction
- TX, TXV, and S-Level Screening Available^{2/}

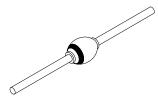
Maximum Ratings		Symbol	Value	Units	
Peak Repetitive Reverse and DC Blocking Voltage		SPD502 SPD503 SPD504 SPD505 SPD506	$egin{aligned} \mathbf{V_{RRM}} \ \mathbf{V_{RWM}} \ \mathbf{V_{R}} \end{aligned}$	200 300 400 500 600	Volts
Average Rectified Forward Current (Resistive Load, 60 Hz, Sine Wave, T _A = 25°C)		Io	5	Amps	
Surge Current (8.3 ms Pulse, Half Sine Wave Superimposed on Io; Allow Junction to Reach Equilibrium between Pulses, $T_A = 25^{\circ}\text{C}$)			I_{FSM}	100	Amps
Operating & Storage Temperature		Top & Tstg	-65 to +175	°C	
Maximum Thermal Resistance		ion to Lead, L=3/8" Junction to End Tab	$egin{array}{c} \mathbf{R}_{ heta \mathrm{JL}} \ \mathbf{R}_{ heta \mathrm{JE}} \end{array}$	15 10	°C/W

Notes:

1/ For Ordering Information, Price, Operating Curves, and Availability – Contact Factory.

2/ Screening Based on MIL-PRF-19500. Screening Flows Available on Request.







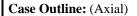


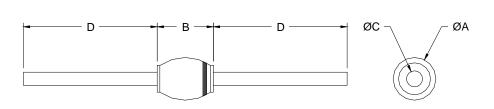
Solid State Devices, Inc.

14701 Firestone Blvd * La Mirada, Ca 90638 Phone: (562) 404-4474 * Fax: (562) 404-1773 ssdi@ssdi-power.com * www.ssdi-power.com

SPD502-SPD506 and SPD502SMS - SPD506SMS

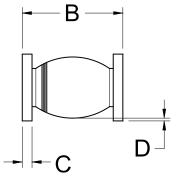
Electrical Characteristics	Symbo	ol Max	Units
Instantaneous Forward Voltage Drop (I _F = 5 Adc, T _A = 25°C, 300 μs pulse)	$\mathbf{V_F}$	1.6	Vdc
Instantaneous Forward Voltage Drop (I _F = 5Adc, T _A = -55°C, 300 µs pulse)	$ m V_{F}$	1.75	Vdc
Reverse Leakage Current (Rated V_R , $T_A = 25$ °C, 300 μ s pulse minimum)	I_R	10	μА
Reverse Leakage Current (Rated V_R , $T_A = 100$ °C, 300 μ s pulse minimum)		1	mA
Junction Capacitance $(V_R = 10 \text{ Vdc}, T_A = 25^{\circ}\text{C}, f = 1\text{MHz})$		50	pF
Reverse Recovery Time $(I_F = 500 \text{ mA}, I_R = 1 \text{A}, I_{RR} = 0.25 \text{A}, T_A = 25 ^{\circ}\text{C})$		40	nsec

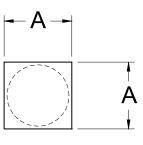




DIMENSIONS					
DIM	MIN	MAX			
A	.140"	.170"			
В	.160"	.230"			
C	.047"	.053"			
D	1.00"				

Case Outline: Surface Mount Square Tab





DIMENSIONS				
DIM	MIN	MAX		
A	.172"	.180"		
В	.195"	.270"		
C	.020"	.035"		
D	.002"			